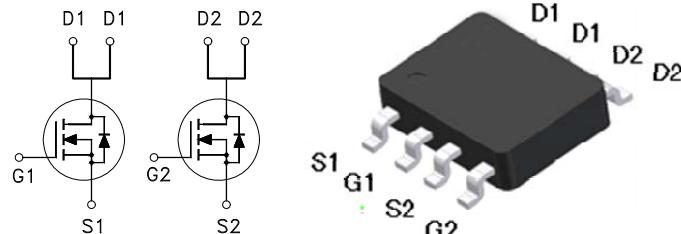


Dual N-Channel Logic Level Enhancement Mode Field Effect Transistor
Product Summary:

| | |
|---------------------|--------------|
| BV_{DSS} | 20V |
| $R_{DS(on)}$ (MAX.) | 20m Ω |
| I_D | 6A |



UIS 100% Tested

Pb-Free Lead Plating & Halogen Free


ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

| PARAMETERS/TEST CONDITIONS | | SYMBOL | LIMITS | UNIT |
|--|--|----------------|------------|------|
| Gate-Source Voltage | | V_{GS} | ± 12 | V |
| Continuous Drain Current | $T_A = 25^\circ\text{C}$ | I_D | 6 | A |
| | $T_A = 100^\circ\text{C}$ | | 4 | |
| Pulsed Drain Current ¹ | | I_{DM} | 24 | |
| Avalanche Current | | I_{AS} | 10 | |
| Avalanche Energy | $L = 0.1\text{mH}, I_D=10\text{A}, R_G=25\Omega$ | E_{AS} | 5 | mJ |
| Repetitive Avalanche Energy ² | $L = 0.05\text{mH}$ | E_{AR} | 2.5 | |
| Power Dissipation | $T_A = 25^\circ\text{C}$ | P_D | 2 | W |
| | $T_A = 100^\circ\text{C}$ | | 0.8 | |
| Operating Junction & Storage Temperature Range | | T_j, T_{stg} | -55 to 150 | °C |

100% UIS testing in condition of $V_D=10\text{V}$, $L=0.1\text{mH}$, $V_G=4.5\text{V}$, $I_L=6\text{A}$, Rated $V_{DS}=20\text{V}$ N-CH
THERMAL RESISTANCE RATINGS

| THERMAL RESISTANCE | SYMBOL | TYPICAL | MAXIMUM | UNIT |
|----------------------------------|-----------------|---------|---------|--------|
| Junction-to-Case | $R_{\theta JC}$ | 25 | 62.5 | °C / W |
| Junction-to-Ambient ³ | $R_{\theta JA}$ | | | |

¹Pulse width limited by maximum junction temperature.²Duty cycle ≤ 1%³62.5°C / W when mounted on a 1 in² pad of 2 oz copper.

ELECTRICAL CHARACTERISTICS ($T_c = 25^\circ\text{C}$, Unless Otherwise Noted)

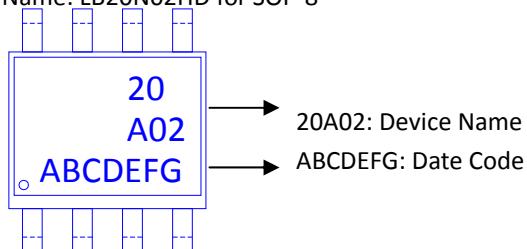
| PARAMETER | SYMBOL | TEST CONDITIONS | LIMITS | | | UNIT |
|---|----------------------|---|--------|-----|-----------|------------------|
| | | | MIN | TYP | MAX | |
| STATIC | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(\text{BR})DSS}$ | $V_{GS} = 0V, I_D = 250\mu\text{A}$ | 20 | | | V |
| Gate Threshold Voltage | $V_{GS(\text{th})}$ | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$ | 0.45 | 0.8 | 1.2 | |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 12V$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = 16V, V_{GS} = 0V$ | | | 1 | μA |
| | | $V_{DS} = 16V, V_{GS} = 0V, T_J = 125^\circ\text{C}$ | | | 25 | |
| On-State Drain Current ¹ | $I_{D(\text{ON})}$ | $V_{DS} = 5V, V_{GS} = 4.5V$ | 6 | | | A |
| Drain-Source On-State Resistance ¹ | $R_{DS(\text{ON})}$ | $V_{GS} = 4.5V, I_D = 6A$ | | 17 | 20 | $\text{m}\Omega$ |
| | | $V_{GS} = 2.5V, I_D = 5A$ | | 23 | 28 | |
| Forward Transconductance ¹ | g_{fs} | $V_{DS} = 5V, I_D = 6A$ | | 8 | | S |
| DYNAMIC | | | | | | |
| Input Capacitance | C_{iss} | $V_{GS} = 0V, V_{DS} = 10V, f = 1\text{MHz}$ | | 560 | | pF |
| Output Capacitance | C_{oss} | | | 166 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 150 | | |
| Total Gate Charge ^{1,2} | Q_g | $V_{DS} = 10V, V_{GS} = 4.5V, I_D = 6A$ | | 8.5 | | nC |
| Gate-Source Charge ^{1,2} | Q_{gs} | | | 1.5 | | |
| Gate-Drain Charge ^{1,2} | Q_{gd} | | | 3.5 | | |
| Turn-On Delay Time ^{1,2} | $t_{d(\text{on})}$ | $V_{DS} = 10V, I_D = 1A, V_{GS} = 4.5V, R_{GS} = 6\Omega$ | | 12 | | nS |
| Rise Time ^{1,2} | t_r | | | 15 | | |
| Turn-Off Delay Time ^{1,2} | $t_{d(\text{off})}$ | | | 30 | | |
| Fall Time ^{1,2} | t_f | | | 13 | | |
| SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_c = 25^\circ\text{C}$) | | | | | | |
| Continuous Current | I_S | | | | 2.3 | A |
| Pulsed Current ³ | I_{SM} | | | | 9.2 | |
| Forward Voltage ¹ | V_{SD} | $I_F = I_S, V_{GS} = 0V$ | | | 1.2 | V |

¹Pulse test : Pulse Width $\leq 300 \mu\text{sec}$, Duty Cycle $\leq 2\%$.²Independent of operating temperature.³Pulse width limited by maximum junction temperature.

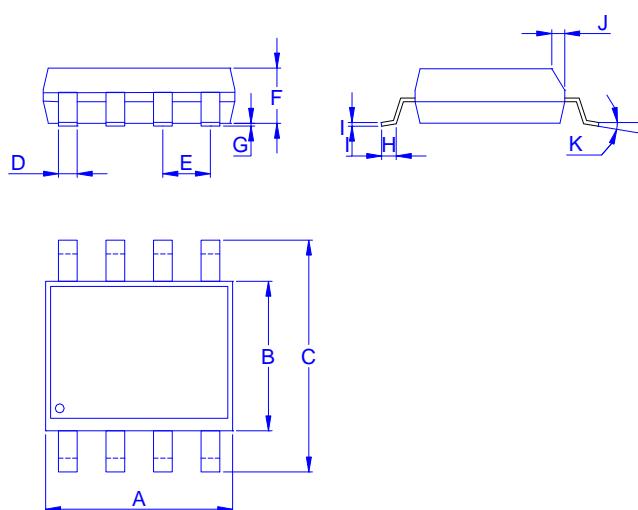
Ordering & Marking

Information:

Device Name: LB20N02HD for SOP-8



Outline Drawing



Dimension in mm

| Dimension | A | B | C | D | E | F | G | H | I | J | K |
|-----------|------|------|------|------|------|------|------|------|------|------|----|
| Min. | 4.70 | 3.70 | 5.80 | 0.33 | | 1.20 | 0.08 | 0.40 | 0.19 | 0.25 | 0° |
| Typ. | | | | | 1.27 | | | | | | |
| Max. | 5.10 | 4.10 | 6.20 | 0.51 | | 1.62 | 0.28 | 0.83 | 0.26 | 0.50 | 8° |

